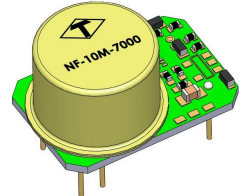


10MHz *Ultra Low Power* OCXO

NF-10M-7000 Series

NF-10M-7000 Series in 20.5x14mm DIP 14 package

NF-10M-7000 series is a 10MHz high performance (VC)OCXO offering ultra low power and tight frequency stability down to $\pm 10\text{ppb}$ (-40°C to $+85^{\circ}\text{C}$). The part comes in a small hermetically sealed through hole package which makes it suitable for humid environmental conditions



FEATURES

- **Ultra Low Power Consumption**
- Tight Frequency Stability
- Fast Warm-up Time
- Low Phase Noise

APPLICATIONS

- High precision GPS receivers
- Portable Wireless Communications
- Mobile Test Equipment
- UHF Synthesizers
- Battery Powered Portable Application

ELECTRICAL SPECIFICATIONS

Test conditions: VDC = +3.3 V; VC = +1.4V; at $+25 \pm 3^{\circ}\text{C}$ unless otherwise identified

1. OUTPUT (PIN = "R.F. OUTPUT")

	Parameter	Min.	Typ.	Max.	Unit	Test Condition
1.1.	Frequency (Fo)	10.000000			MHz	
1.2.	Initial Accuracy	-0.2		+0.2	ppm	@ $+25 \pm 3^{\circ}\text{C}$ 30 minutes after turn on Vcon=+1.4V
1.3.	Waveform	CMOS				
1.4.	Level				V	
	"1" level	2.4				
	"0" level			0.4		
1.5.	Rise/Fall Time			10	nSec.	
1.6.	Duty Cycle	45		55	%	
1.7.	Load	10K Ω /15pF				

2. FREQUENCY STABILITY

	Parameter	Min.	Typ.	Max.	Unit	Test Condition	
2.1.	Ambient	±10			ppb	referred to 25°C	
		-40°C ~ +85°C			°C		
2.2.	Aging						
	Daily	-0.3		+0.3	ppb	after 30 days	+/-0.2ppb/day optional
	Yearly	-30		+30	ppb		
2.3.	Voltage	-2		+2	ppb	±5% change	
2.4.	Short term		0.04		ppb	root Allan variance for τ=1 sec	
2.5.	Warm-up	-100		+100	ppb	in 60 seconds @ +25 ±3°C	referred to 15 minutes
2.6.	G-Sensitivity (each axis)		±1		ppb/g		
2.7.	Phase Noise (Max.)			-95	dBc/Hz	@ 1Hz	
				-125	dBc/Hz	@ 10Hz	
				-145	dBc/Hz	@ 100Hz	
				-155	dBc/Hz	@ 1KHz	
				-165	dBc/Hz	@ 10KHz	
				-165	dBc/Hz	@ 100KHz	

3. ELECTRICAL FREQUENCY ADJUSTMENT (PIN = "VCON")

	Parameter	Min.	Typ.	Max.	Unit	Test Condition	
3.1.	Tuning Range	± 0.4			ppm	Referenced to frequency at nominal Center Voltage	
3.2.	Control Voltage	0		+2.8	V		
3.3.	Slope	Positive					
3.4.	Center Voltage		+1.4		V		
3.5.	Linearity	-10		+10	%		

4. INPUT POWER (PIN = "+V_{DD}")

	Parameter	Min.	Typ.	Max.	Unit	Test Condition	
4.1.	Voltage	+3.13	+3.3	+3.47	V		
4.2.	Power Consumption						
	Steady State		120	150	mW	at 25°C	
	During Warm-Up			450			

5. REFERENCE VOLTAGE (PIN = "REFERENCE VOLTAGE")

	Parameter	Min.	Typ.	Max.	Units	Test Condition	
5.1.	Voltage	+2.7	+2.8	+2.9	V		

6. ABSOLUTE MAXIMUM RATINGS

	Parameter	Min.	Typ.	Max.	Units	Test Condition	
6.1.	Input Power(V _{DD})	-0.3		+6.0	V		
6.2.	Control Voltage (VCON)	-1.0		+6.0	V		

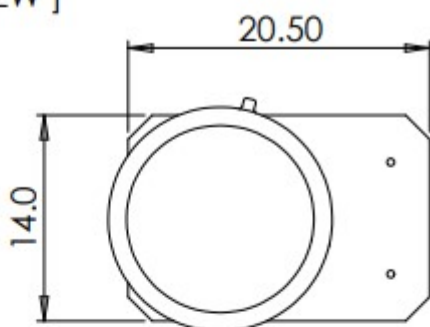
7. ENVIRONMENTAL

	Parameter	Reference Std.	Test Condition
7.1.	Operable Temperature	-40°C to +85°C	Note 1
7.2.	Storage Temperature	-45°C to +90°C	
7.3.	Humidity	MIL-STD-202, Method 103 Test Condition A	95% RH @ +40°C, non-condensing, 240 hours
7.4.	Vibration (non-operating)	MIL-STD-202, Method 201	0.06" Total p-p, 10 to 55 Hz
7.5.	Shock (non-operating)	MIL-STD-202, Method 213, Test Condition J	30g, 11ms, half-sine 1500g, 1ms, half-sine optional
7.6.	Reflow is Forbidden	Hand solder only – not reflow compatible. 260°C 10s (on pins)	

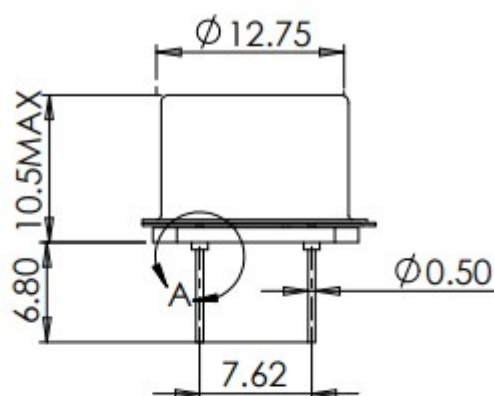
Note 1 : Output maintained over this temperature range. Other requirements of this specification may not be met when operating outside the temperature range in 2.1.

OUTLINE DRAWING

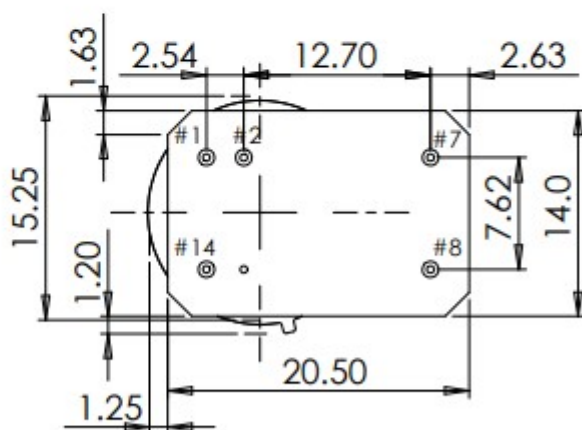
[TOP VIEW]



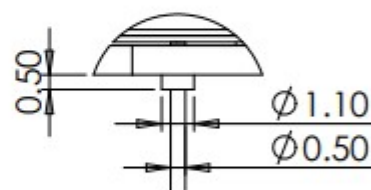
[SIDE VIEW]



[BOTTOM VIEW]



unit:mm
All Tolerances : 0.254mm



DETAIL A(4:1)

PIN	Function
1	V _{con}
2	V _{REF}
7	GND
8	Output
14	V _{DD}